

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
900V	$2.5\Omega@10V$	0.5A

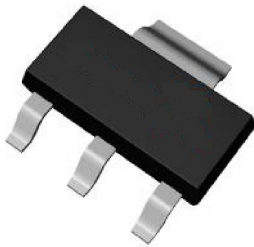
Feature

- Low On-Resistance
- Fast Switching Speed
- Ultra-fast Body Diode
- Very High Commutation Ruggedness

Application

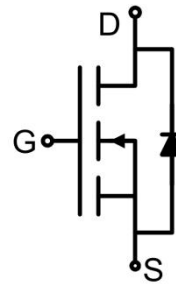
- DC-AC Inverters
- PC power
- Telecom/Server
- Solar Inverter

Package

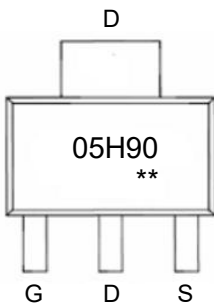


SOT-223

Circuit diagram



Marking



Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	900	V
Gate-Source Voltage	V_{GS}	±30	V
Continuous Drain Current	I_D	0.5	A
Pulsed Drain Current	I_{DM}	2	A
Power Dissipation	P_D	4.2	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	29.8	°C/W
Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55 ~ +150	°C

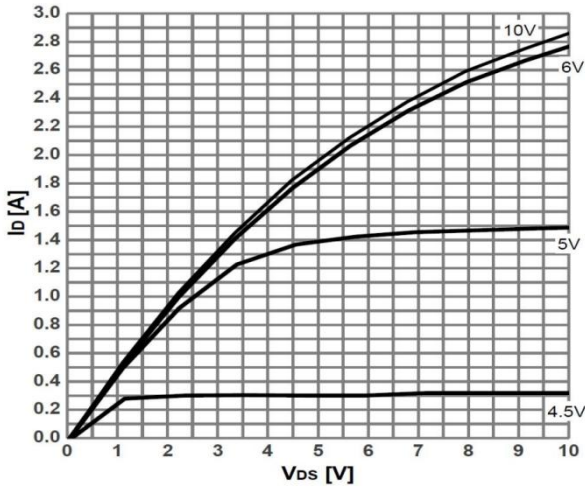
Electrical characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	900			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 900V, V_{GS} = 0V$			1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$			±100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	2	3	4	V
Drain-source on-resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 0.2A$		2.1	2.5	Ω
Dynamic characteristics¹⁾						
Input Capacitance	C_{iss}	$V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$		382		pF
Output Capacitance	C_{oss}			18		
Reverse Transfer Capacitance	C_{rss}			2.5		
Total Gate Charge	Q_g	$V_{DS} = 15V, V_{GS} = 10V, I_D = 0.5A$		15		nC
Gate-Source Charge	Q_{gs}			1.4		
Gate-Drain Charge	Q_{gd}			13		
Turn-on delay time	$t_{d(on)}$	$V_{DD} = 15V, V_{GS} = 10V, I_D = 0.5A$ $R_L = 2.6\Omega, R_{GEN} = 3\Omega$		78		nS
Turn-on rise time	t_r			19		
Turn-off delay time	$t_{d(off)}$			28		
Turn-off fall time	t_f			31		
Source-Drain Diode characteristics						
Diode Forward voltage	V_{SD}	$V_{GS} = 0V, I_S = 0.5A$			1.2	V

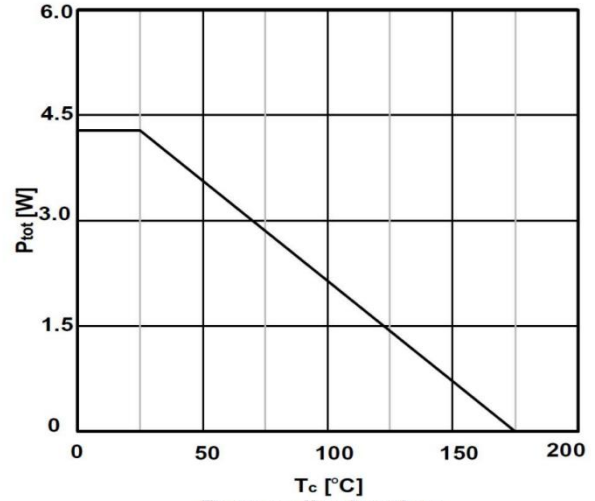
Notes:

1) Guaranteed by design, not subject to production.

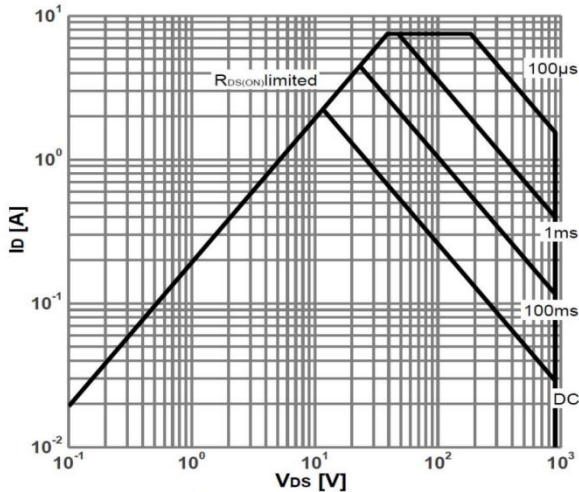
Typical Characteristics



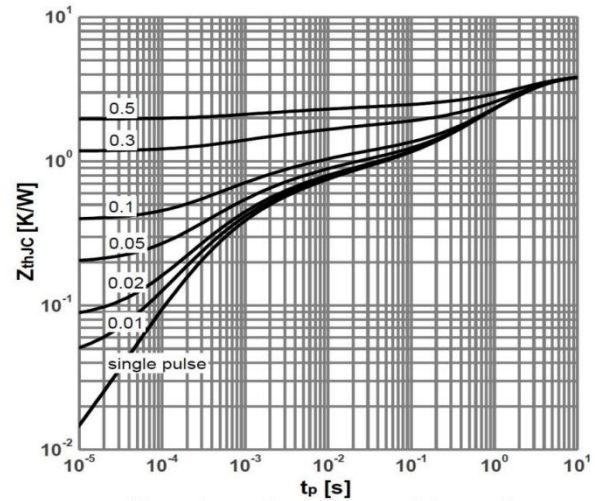
Output characteristics



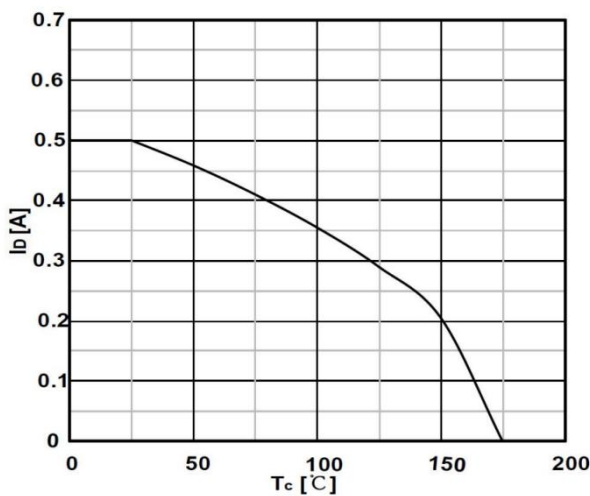
Power dissipation



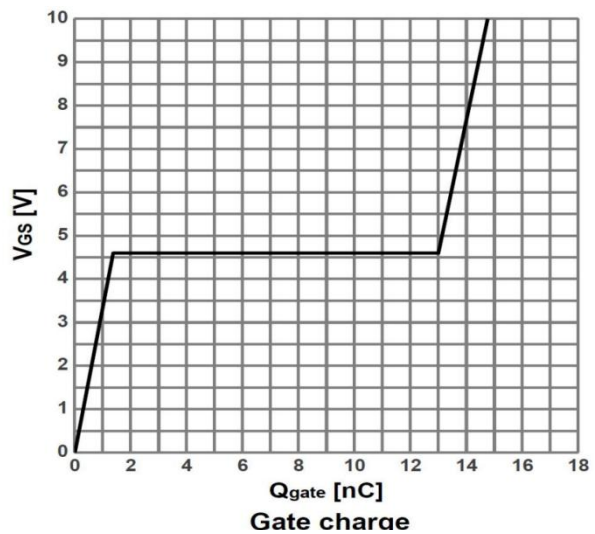
Safe operating area



Max. transient thermal impedance

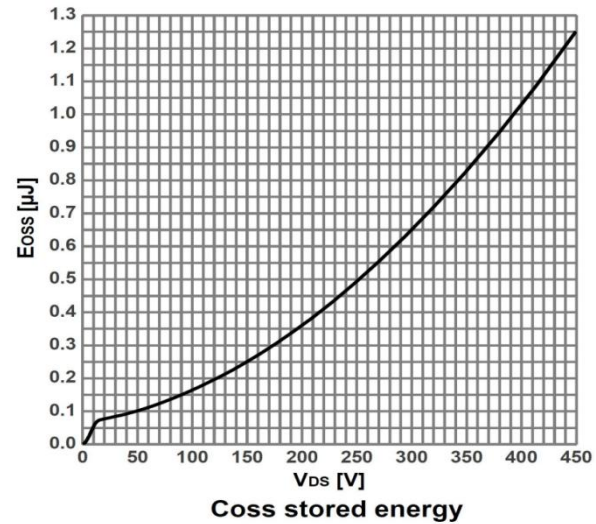
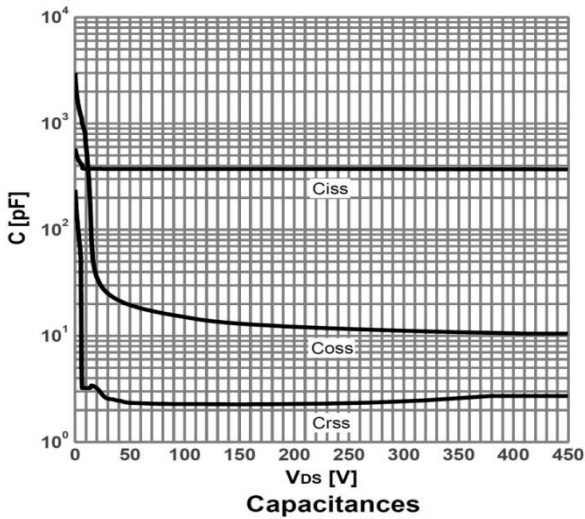
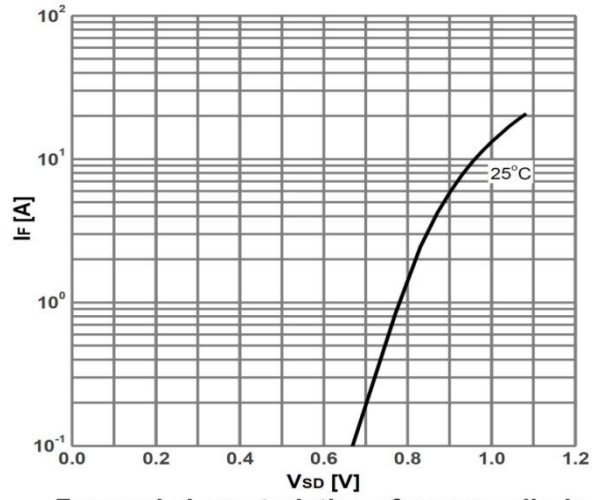
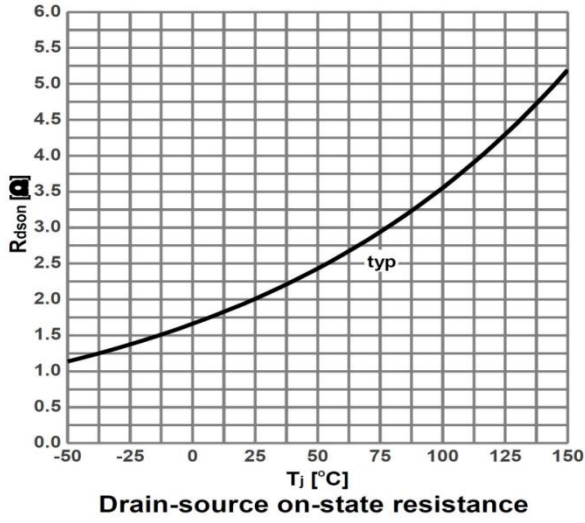


Current dissipation

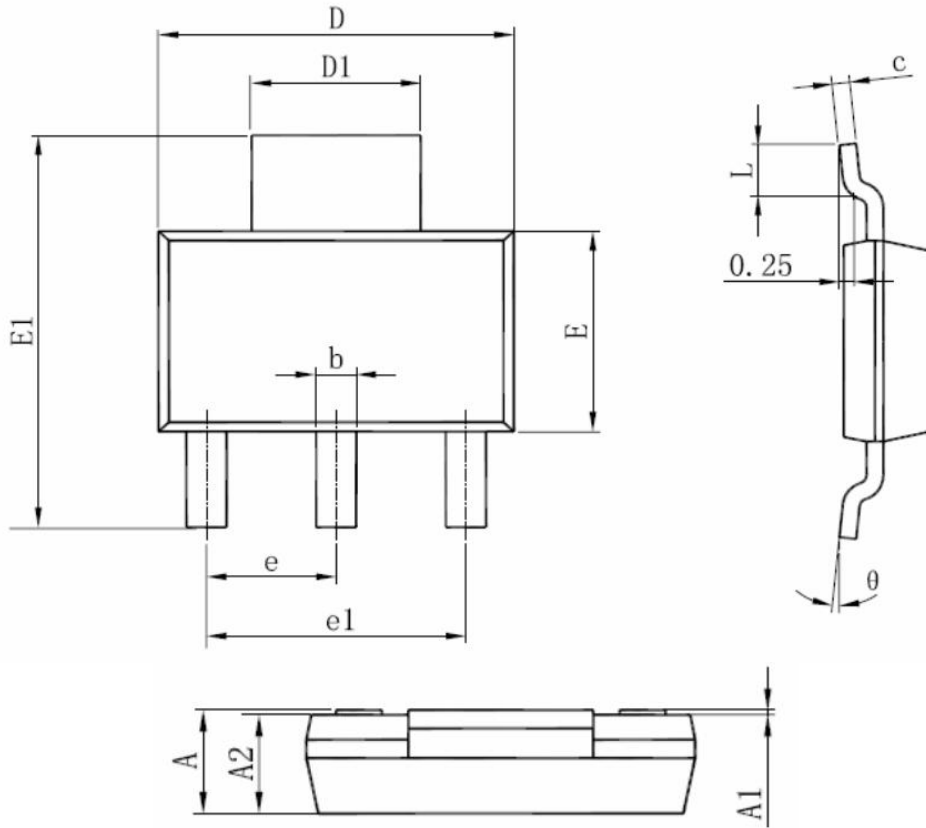


Gate charge

Typical Characteristics



SOT-223 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.520	1.800	0.060	0.071
A1	0.000	0.100	0.000	0.004
A2	1.500	1.700	0.059	0.067
b	0.660	0.820	0.026	0.032
c	0.250	0.350	0.010	0.014
D	6.200	6.400	0.244	0.252
D1	2.900	3.100	0.114	0.122
E	3.300	3.700	0.130	0.146
E1	6.830	7.070	0.269	0.278
e	2.300(BSC)		0.091(BSC)	
e1	4.500	4.700	0.177	0.185
L	0.900	1.150	0.035	0.045
θ	0°	10°	0°	10°